

# FGB5N60UNDF

## 600 V, 5 A

### Short Circuit Rated IGBT



### General Description

Using advanced NPT IGBT technology, Fairchild®'s the NPT IGBTs offer the optimum performance for low-power inverter-driven applications where low-losses and short-circuit ruggedness features are essential, such as sewing machine, CNC, motor control and home appliances.

### Features

- Short Circuit Rated 10 us
- High Current Capability
- High Input Impedance
- Fast Switching
- RoHS Compliant

### Applications

- Sewing Machine, CNC, Home Appliances, Motor Control



### Absolute Maximum Ratings

Symbol	Description	Ratings	Unit
$V_{CES}$	Collector to Emitter Voltage	600	V
$V_{GES}$	Gate to Emitter Voltage	$\pm 20$	V
$I_C$	Collector Current @ $T_C = 25^\circ\text{C}$	10	A
	Collector Current @ $T_C = 100^\circ\text{C}$	5	A
$I_{CM(1)}$	Pulsed Collector Current @ $T_C = 25^\circ\text{C}$	15	A
$I_F$	Diode Forward Current @ $T_C = 25^\circ\text{C}$	5	A
$P_D$	Maximum Power Dissipation @ $T_C = 25^\circ\text{C}$	73.5	W
	Maximum Power Dissipation @ $T_C = 100^\circ\text{C}$	29.4	W
$T_J$	Operating Junction Temperature	-55 to +150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
$T_L$	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	$^\circ\text{C}$

**Notes:**  
1: Repetitive rating: Pulse width limited by max. junction temperature

### Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JC}(\text{IGBT})$	Thermal Resistance, Junction to Case		1.7	$^\circ\text{C}/\text{W}$
$R_{\theta JC}(\text{Diode})$	Thermal Resistance, Junction to Case		4.5	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (PCB Mount)(2)		40	$^\circ\text{C}/\text{W}$

**Notes:**  
2: Mounted on 1" square PCB (FR4 or G-10 material)

## Package Marking and Ordering Information

Device Marking	Device	Package	Rel Size	Tape Width	Quantity
FGB5N60UNDF	FGB5N60UNDF	TO-263AB/D2-PAK		-	50

## Electrical Characteristics of the IGBT T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
<b>Off Characteristics</b>						
$V_{CES}$	Collector to Emitter Breakdown Voltage	$V_{GE} = 0V, I_C = 250\mu A$	600	-	-	V
$I_{CES}$	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0V$	-	-	1	mA
$I_{GES}$	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0V$	-	-	±10	uA
<b>On Characteristics</b>						
$V_{GE(th)}$	G-E Threshold Voltage	$I_C = 5mA, V_{CE} = V_{GE}$	5.5	6.8	8.5	V
$V_{CE(sat)}$	Collector to Emitter Saturation Voltage	$I_C = 5A, V_{GE} = 15V$	-	1.9	2.4	V
		$I_C = 5A, V_{GE} = 15V, T_C = 125^\circ C$	-	2.3	-	V
<b>Dynamic Characteristics</b>						
$C_{ies}$	Input Capacitance	$V_{CE} = 30V, V_{GE} = 0V, f = 1MHz$	-	181		pF
$C_{oes}$	Output Capacitance		-	28		pF
$C_{res}$	Reverse Transfer Capacitance		-	7		pF
<b>Switching Characteristics</b>						
$t_{d(on)}$	Turn-On Delay Time	$V_{CC} = 400V, I_C = 5A, R_G = 10\Omega, V_{GE} = 15V, \text{Inductive Load}, T_C = 25^\circ C$	-	5.4		ns
$t_r$	Rise Time		-	1.9		ns
$t_{d(off)}$	Turn-Off Delay Time		-	25.4		ns
$t_f$	Fall Time		-	101	202	ns
$E_{on}$	Turn-On Switching Loss		-	0.08		mJ
$E_{off}$	Turn-Off Switching Loss		-	0.07		mJ
$E_{ts}$	Total Switching Loss	-	0.15		mJ	
$t_{d(on)}$	Turn-On Delay Time	$V_{CC} = 400V, I_C = 5A, R_G = 10\Omega, V_{GE} = 15V, \text{Inductive Load}, T_C = 125^\circ C$	-	5.2		ns
$t_r$	Rise Time		-	2.3		ns
$t_{d(off)}$	Turn-Off Delay Time		-	26.6		ns
$t_f$	Fall Time		-	125		ns
$E_{on}$	Turn-On Switching Loss		-	0.15		mJ
$E_{off}$	Turn-Off Switching Loss		-	0.09		mJ
$E_{ts}$	Total Switching Loss	-	0.24		mJ	
$T_{sc}$	Short Circuit Withstand Time	$V_{CC} = 350V, R_G = 100\Omega, V_{GE} = 15V, T_C = 150^\circ C$	10	-	-	μs

**Electrical Characteristics of the IGBT**  $T_C = 25^\circ\text{C}$  unless otherwise noted

$Q_g$	Total Gate Charge	$V_{CE} = 400\text{V}, I_C = 5\text{A},$ $V_{GE} = 15\text{V}$	-	12.1		nC
$Q_{ge}$	Gate to Emitter Charge		-	1.7		nC
$Q_{gc}$	Gate to Collector Charge		-	7.2		nC

**Electrical Characteristics of the Diode**  $T_C = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max	Unit	
$V_{FM}$	Diode Forward Voltage	$I_F = 5\text{A}$	$T_C = 25^\circ\text{C}$	-	1.7	2.2	V
			$T_C = 125^\circ\text{C}$	-	1.6	-	
$t_{rr}$	Diode Reverse Recovery Time	$I_F = 5\text{A}, di_F/dt = 200\text{A}/\mu\text{s}$	$T_C = 25^\circ\text{C}$	-	35		ns
			$T_C = 125^\circ\text{C}$	-	87		
$Q_{rr}$	Diode Reverse Recovery Charge		$T_C = 25^\circ\text{C}$	-	71		nC
			$T_C = 125^\circ\text{C}$	-	240	-	

## Typical Performance Characteristics

Figure 1. Typical Output Characteristics

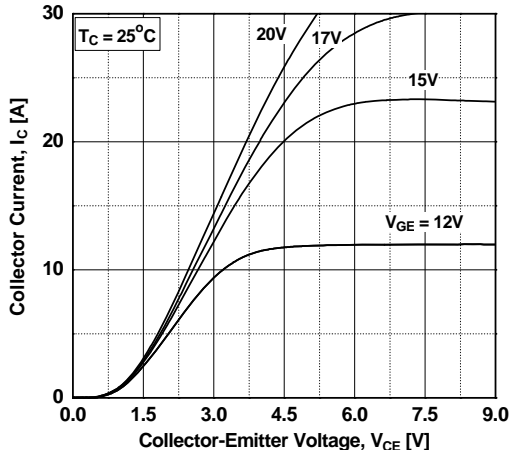


Figure 2. Typical Output Characteristics

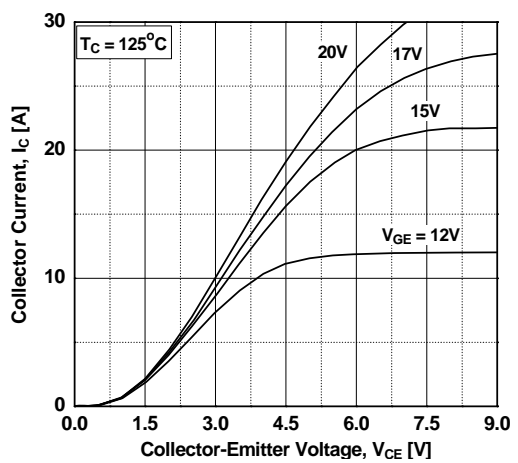


Figure 3. Typical Saturation Voltage Characteristics

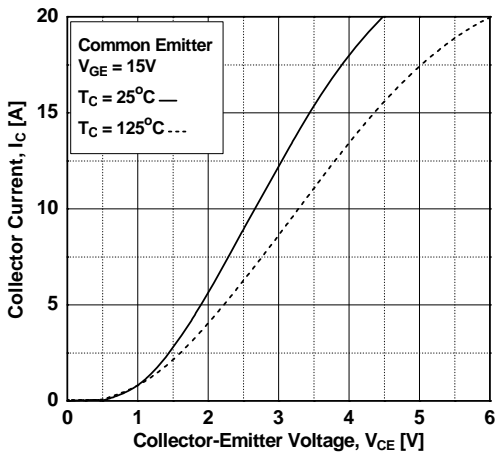


Figure 4. Transfer Characteristics

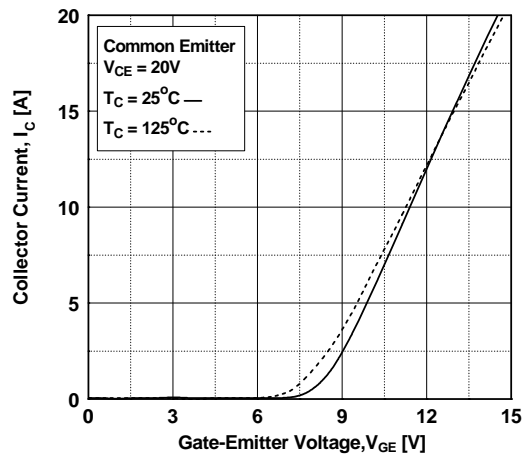


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

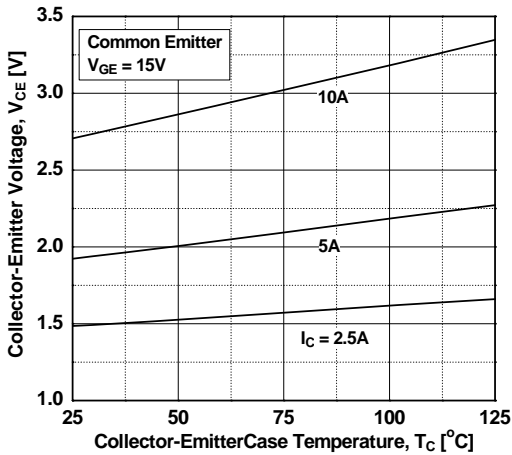
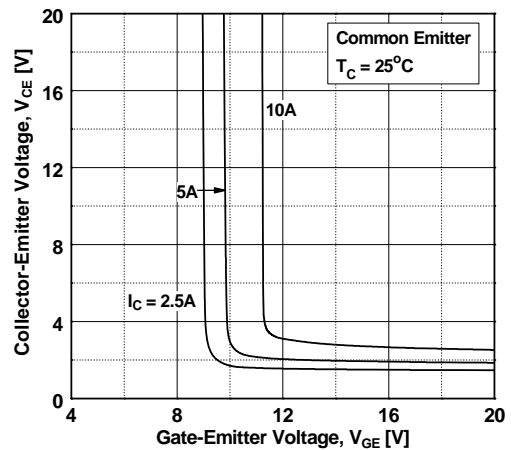


Figure 6. Saturation Voltage vs. Vge



## Typical Performance Characteristics

Figure 7. Saturation Voltage vs.  $V_{GE}$

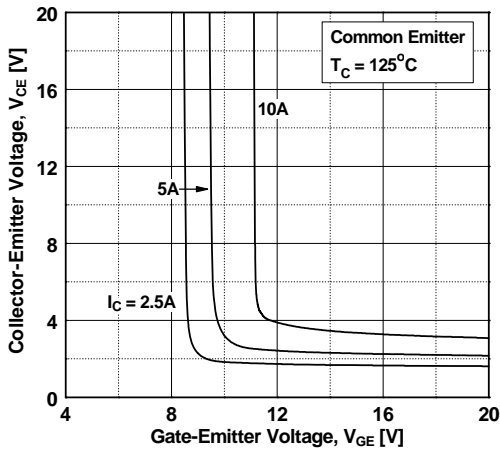


Figure 8. Capacitance Characteristics

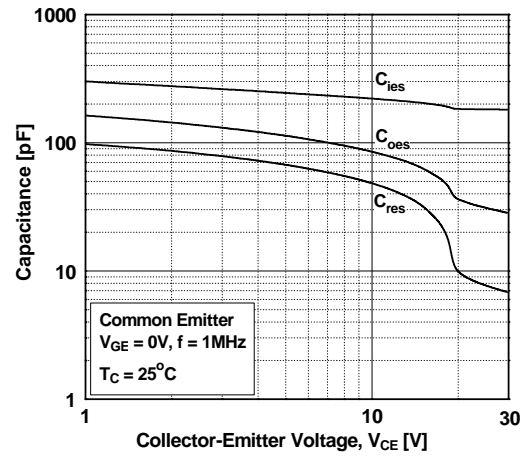


Figure 9. Gate charge Characteristics

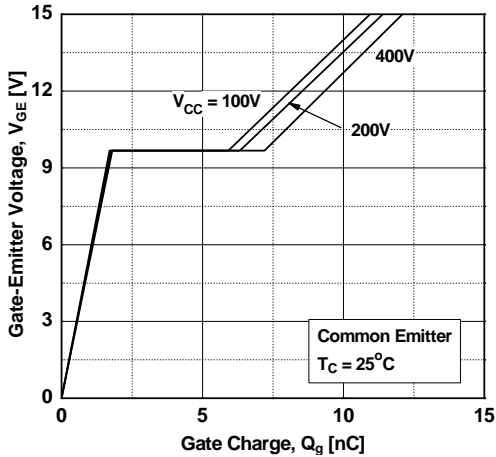


Figure 10. SOA Characteristics

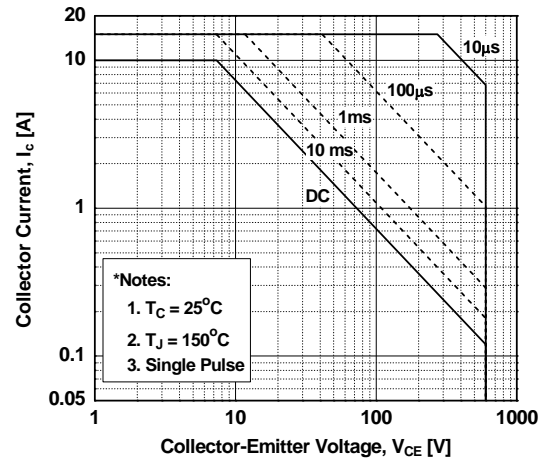


Figure 11. Turn-on Characteristics vs. Gate Resistance

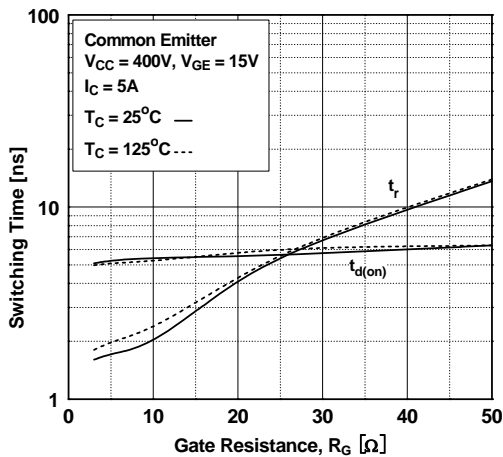
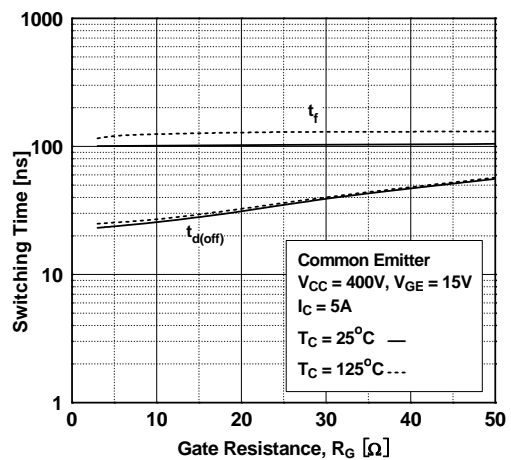
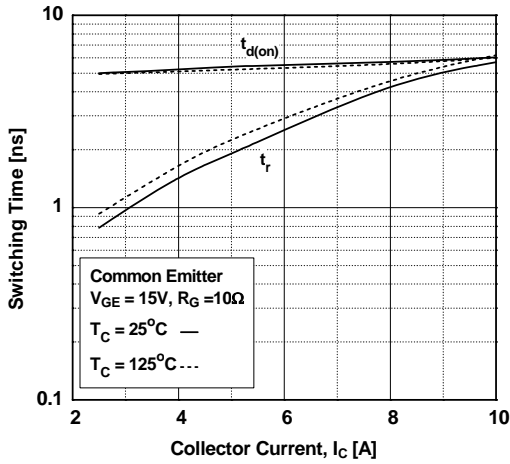


Figure 12. Turn-off Characteristics vs. Gate Resistance

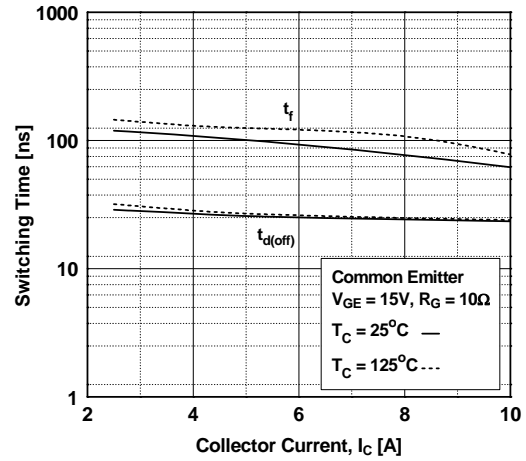


## Typical Performance Characteristics

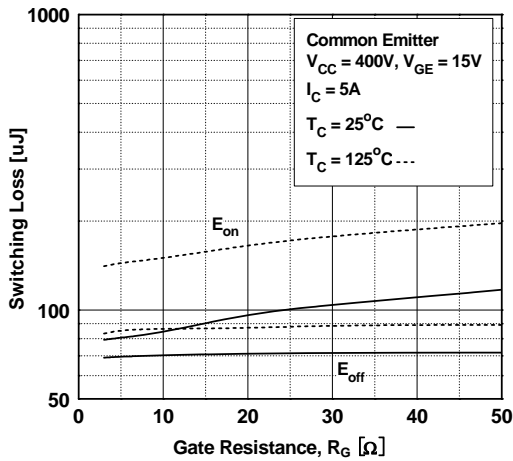
**Figure 13. Turn-on Characteristics vs. Collector Current**



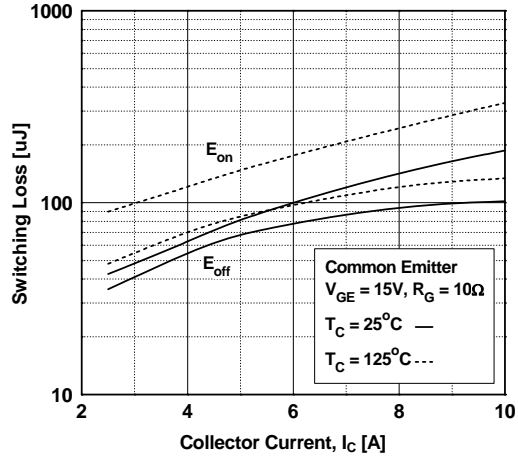
**Figure 14. Turn-off Characteristics vs. Collector Current**



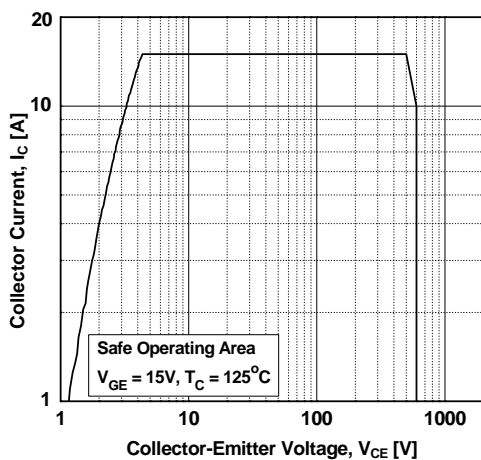
**Figure 15. Switching Loss vs. Gate Resistance**



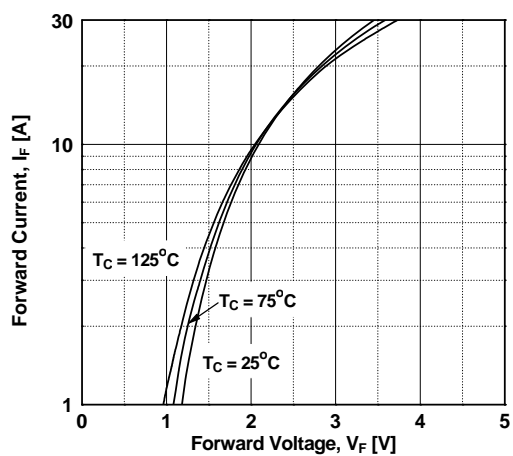
**Figure 16. Switching Loss vs. Collector Current**



**Figure 17. Turn off Switching SOA Characteristics**



**Figure 18. Forward Characteristics**



## Typical Performance Characteristics

Figure 19. Reverse Recovery Current

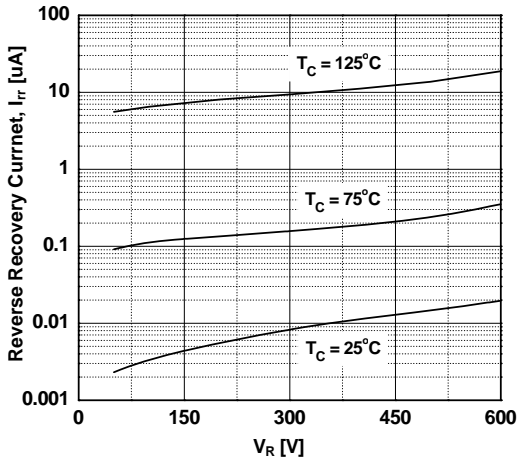


Figure 20. Stored Charge

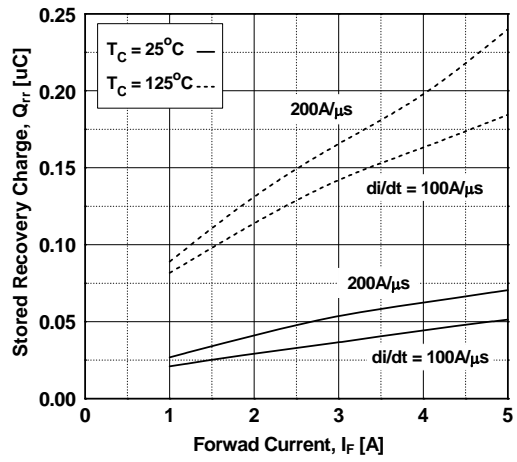


Figure 21. Reverse Recovery Time

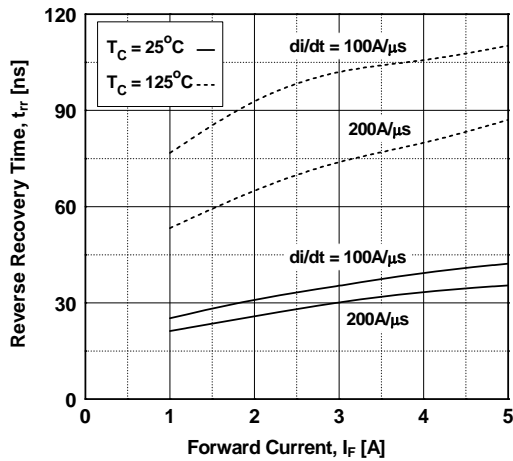
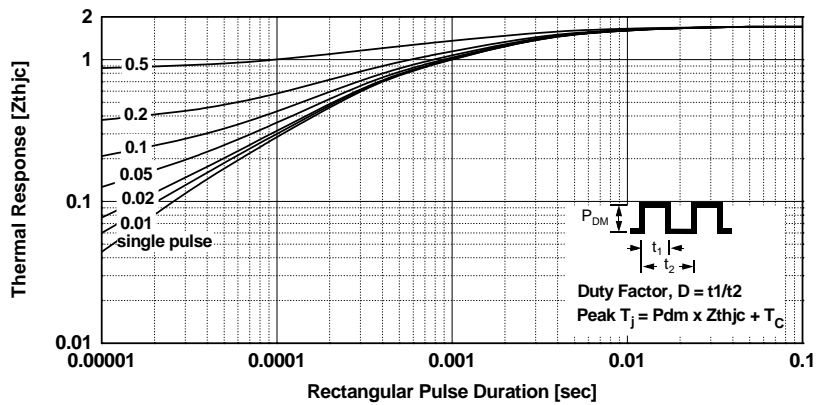
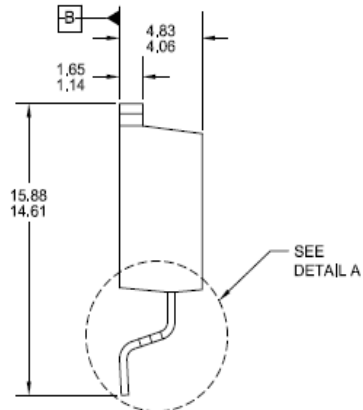
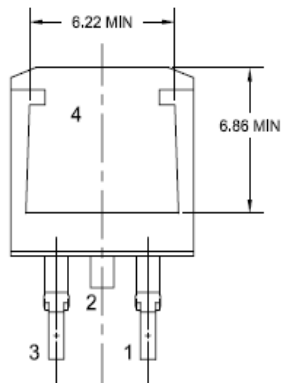
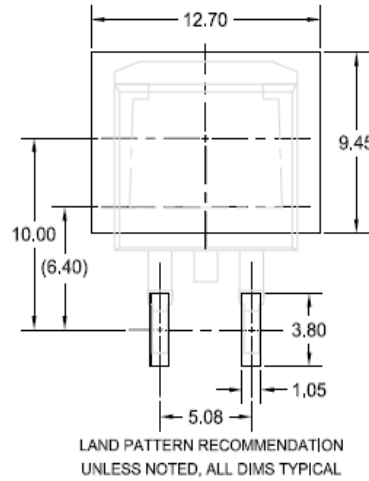
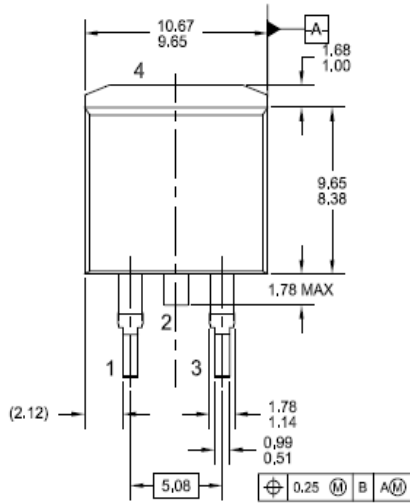


Figure 23. Transient Thermal Impedance of IGBT

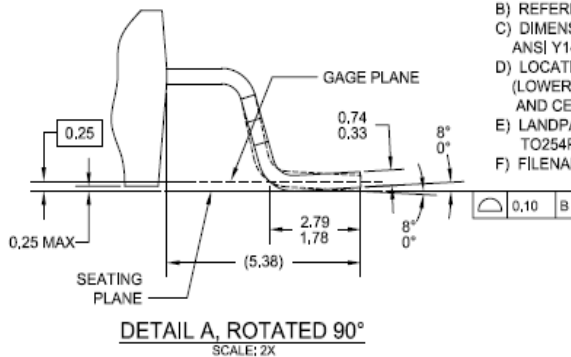


**Mechanical Dimensions**

**TO-263AB/D<sup>2</sup>-PAK**




- NOTES: UNLESS OTHERWISE SPECIFIED  
 A) ALL DIMENSIONS ARE IN MILLIMETERS.  
 B) REFERENCE JEDEC, TO-263, VARIATION AB.  
 C) DIMENSIONING AND TOLERANCING PER ANSI Y14.5M - 1994.  
 D) LOCATION OF THE PIN HOLE MAY VARY (LOWER LEFT CORNER, LOWER CENTER AND CENTER OF THE PACKAGE).  
 E) LANDPATTERN RECOMMENDATION PER IPC TO254P1524X482-3N  
 F) FILENAME: TO263A02REV6





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| AX-CAP®*  | FRFET®  | Programmable Active Droop™            | TinyBoost™       |
| BitSiC™   | Global Power ResourceSM                         | QFET®                                 | TinyBuck™        |
| Build it Now™   | Green Bridge™                                   | QST™                                  | TinyCalc™        |
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| CorePOWER™  | Green FPS™ e-Series™                            | RapidConfigure™                       | TINYOPTO™        |
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| FAST®   | OptoHiT™  |                                       | XS™              |
| FastvCore™  | OPTOLOGIC®                                      |                                       |                  |
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Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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